

Features

- · Split Gate Trench MOSFET Technology
- Low R_{DS(on)} & FOM
- · Extremely Low Switching Loss
- Excellent Stability and Uniformity
- Halogen Free. "Green" Device (Note 1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- · Moisture Sensitivity Level 1

Maximum Ratings

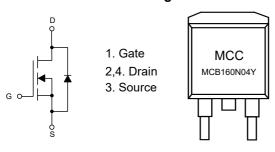
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 70°C/W Junction to Ambient⁽¹⁾
- Thermal Resistance: 0.8°C/W Junction to Case

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V _{DS}	40	V	
Gate-Source Volltage		V _{GS}	±20	V
Continuous Drain	T _C =25°C		160	Α
Current ⁽²⁾	T _C =100°C	– I _D	100	Α
Pulsed Drain Current (3)		I _{DM}	480	Α
Avalanche Energy (4)		E _{AS}	720	mJ
Total Power Dissipation (5)		P _D	P _D 150	

Note:

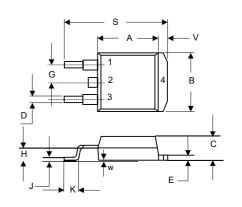
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The Power dissipation P_{DSM} is based on $R_{\theta JA}$ t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. T_J =25°C, V_{DD} =25V, L=3mH, I_{AS} =22A

Internal Structure and Marking Code



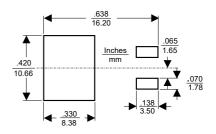
N-CHANNEL MOSFET

D2-PAK



DIMENSIONS					
DIM INC		HES	MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.331	0.370	8.40	9.40	
В	0.378	0.417	9.60	10.60	
С	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
Е	0.045	0.055	1.14	1.40	
G	0.010		2.54		TYP.
Ι	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

Suggested Solder Pad Layout



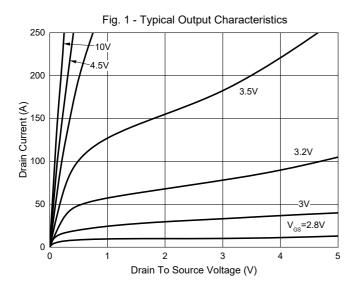


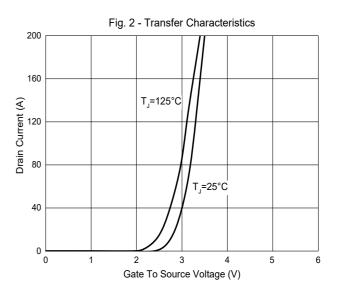
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

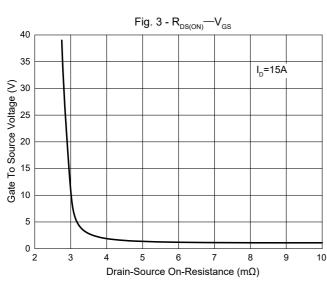
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics					1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	40			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.8	2.5	V	
Drain-Source On-Resistance		V _{GS} =10V, I _D =20A		1.5	1.85	mΩ	
	R _{DS(on)}	V _{GS} =4.5V, I _D =20A		2.3	2.8		
Diode Characteristics			<u> </u>				
Continuous Body Diode Current	Is				160	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.3	V	
Reverse Recovery Time	t _{rr}	- I _F =20A, dI _F /dt=100A/μs		56		ns	
Reverse Recovery Charge	Q_{rr}	اب-201, مابالا-1001/43		54		nC	
Dynamic Characteristics					•		
Input Capacitance	C _{iss}			7100		pF	
Output Capacitance	C _{oss}	V _{DS} =25V,V _{GS} =0V,f=1MHz		1298			
Reverse Transfer Capacitance	C _{rss}			55			
Total Gate Charge	Q_g			132			
Gate-Source Charge	Q _{gs}	V _{DS} =20V,I _D =20A		25		nC	
Gate-Drain Charge	Q_{gd}			24.6			
Turn-On Delay Time	t _{d(on)}			18.8			
Turn-On Rise Time	t _r	V_{DS} =20V, V_{GS} =10V, R_{G} =2.2 Ω , I_{DS} =20A		70		no	
Turn-Off Delay Time	t _{d(off)}			136.8		ns	
Turn-Off Fall Time	t _f			92.3			

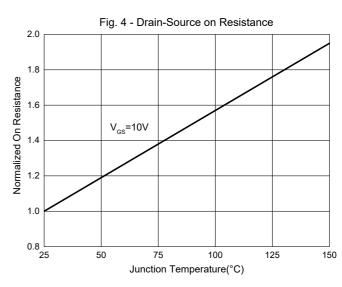


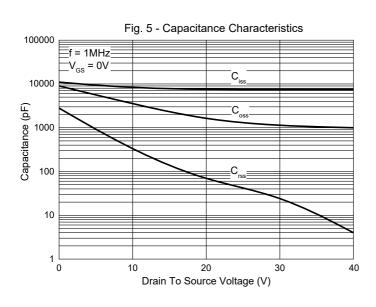
Curve Characteristics

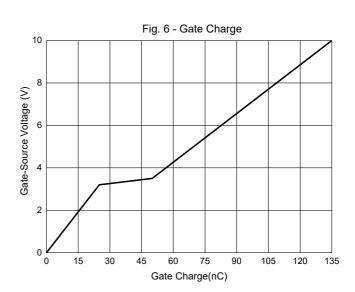






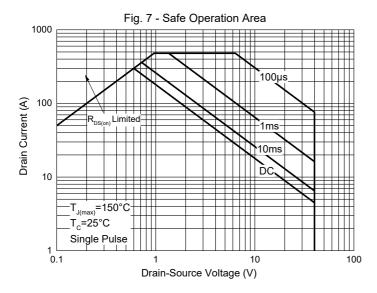


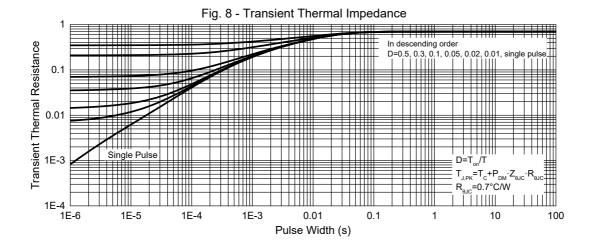






Curve Characteristics





Rev.3-2-04092022 4/5 MCCSEMI.COM



Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 800pcs/Reel	
Part Number-BP	Tube: 5Kpcs/Ctn	

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